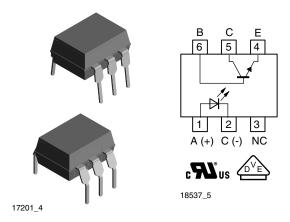


### Vishay Semiconductors

## **Optocoupler, Phototransistor Output, with Base Connection**



### DESCRIPTION

The CNY75A, CNY75B, CNY75C, CNY75GA, CNY75GB, CNY75GC consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 6 pin plastic dual inline package.

### AGENCY APPROVALS

- UL1577, file no. E52744, double protection
- BSI: BS EN 41003, BS EN 60095 (BS 415), BS EN 60950 (BS 7002), pending
- DIN EN 60747-5-5 (VDE 0884)
- FIMKO (SETI): EN 60950, certificate no. FI25155

### FEATURES

- Isolation materials according to UL 94-VO
- Pollution degree 2 (DIN/VDE 0110/resp. IEC 60664)
- Climatic classification 55/110/21 (IEC 60068 part 1)
- Low temperature coefficient of CTR
- CTR offered in 3 groups
- Rated isolation voltage (RMS includes DC) V<sub>IOWM</sub> = 600 V<sub>RMS</sub> (848 V peak)
- Rated recurring peak voltage (repetitive)  $V_{IORM} = 600 V_{RMS}$
- Rated impulse voltage (transient overvoltage)  $V_{IOTM} = 6 kV_{peak}$
- Isolation test voltage (partial discharge test voltage)  $V_{pd}$  = 1.6 kV
- Creepage current resistance according to VDE 0303/ IEC 60112 comparative tracking index: CTI  $\geq$  325
- Thickness through insulation  $\ge 0.4 \text{ mm}$
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **APPLICATIONS**

- · Switch-mode power supplies
- Line receiver
- · Computer peripheral interface
- · Microprocessor system interface
- Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):
- for appl. class I IV at mains voltage  $\leq 300~V$
- for appl. class I III at mains voltage  $\leq 600~V$
- according to DIN EN 60747-5-5 (VDE 0884)

ORDER INFORMATION <sup>(1)</sup>					
PART	REMARKS				
CNY75A	CTR 63 % to 125 %, DIP-6				
CNY75B	CTR 100 % to 200 %, DIP-6				
CNY75C	CTR 160 % to 320 %, DIP-6				
CNY75GA	CTR 63 % to 125 %, DIP-6, 400 mil				
CNY75GB	CTR 100 % to 200 %, DIP-6, 400 mil				
CNY75GC	CTR 160 % to 320 %, DIP-6, 400 mil				

#### Note

<sup>(1)</sup> G = leadform 10.16 mm; G is not marked on the body.



ROHS COMPLIANT



Optocoupler, Phototransistor Output, Vishay Semiconductors with Base Connection

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
	TEST CONDITION	STWBOL	VALUE	UNIT
INPUT				
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	60	mA
Forward surge current	$t_p \le 10 \ \mu s$	I <sub>FSM</sub>	3	А
Power dissipation		P <sub>diss</sub>	70	mW
Junction temperature		Т <sub>і</sub>	125	°C
OUTPUT	·	·	• •	
Collector base voltage		V <sub>CBO</sub>	70	V
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		Ι <sub>C</sub>	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Power dissipation		P <sub>diss</sub>	70	mW
Junction temperature		Т <sub>і</sub>	125	°C
COUPLER		,		
AC isolation test voltage (RMS)		V <sub>ISO</sub>	5000	V <sub>RMS</sub>
Total power dissipation		P <sub>tot</sub>	200	mW
Ambient temperature range		T <sub>amb</sub>	- 55 to + 110	°C
Storage temperature range		T <sub>stg</sub>	- 55 to + 125	°C
Soldering temperature <sup>(2)</sup>	2 mm from case, t $\leq$ 10 s	T <sub>sld</sub>	260	°C

#### Notes

 $^{(1)}$  T<sub>amb</sub> = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices.

ELECTRICAL CHARACTERISTCS <sup>(1)</sup>								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I <sub>F</sub> = 50 mA		VF		1.25	1.6	V	
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>			10	μΑ	
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		Cj		50		pF	
OUTPUT								
Collector base voltage	I <sub>C</sub> = 100 μA		V <sub>CBO</sub>	70			V	
Collector emitter voltage	$I_{\rm C} = 1  \rm{mA}$		V <sub>CEO</sub>	70			V	
Emitter collector voltage	I <sub>E</sub> = 100 μA		V <sub>ECO</sub>	7			V	
Collector emitter leakage current	V <sub>CE</sub> = 20 V, I <sub>F</sub> = 0 A		I <sub>CEO</sub>			150	nA	
COUPLER								
Collector emitter saturation voltage	$I_{\rm F} = 10 \text{ mA}, I_{\rm C} = 1 \text{ mA}$		V <sub>CEsat</sub>			0.3	V	
Cut-off frequency	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 10 \text{ mA},$ $R_{L} = 100 \Omega$		f <sub>c</sub>		110		kHz	
Coupling capacitance	f = 1 MHz		C <sub>k</sub>		0.6		pF	

#### Note

<sup>(1)</sup>  $T_{amb} = 25 \text{ °C}$ , unless otherwise specified.

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.



Vishay Semiconductors Optocoupler, Phototransistor Output, with Base Connection

CURRENT TRANSFER RATIO									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
I <sub>C</sub> /I <sub>F</sub>		CNY75GA	CTR	15			%		
	$V_{CE} = 5 \text{ V}, \text{ I}_{F} = 1 \text{ mA}$	CNY75GB	CTR	30			%		
		CNY75GC	CTR	60			%		
		CNY75GA	CTR	63		125	%		
	$V_{CE} = 5 V, I_F = 10 mA$	CNY75GB	CTR	100		200	%		
		CNY75GC	CTR	160		320	%		

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		CNY75GA	I <sub>F</sub>		10		mA
Current time	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 100 \Omega$	CNY75GB	١ <sub>F</sub>		10		mA
		CNY75GC	I <sub>F</sub>		10		mA
		CNY75GA	t <sub>d</sub>		2		μs
Delay time	$V_{CC}$ = 5 V, $R_L$ = 100 $\Omega$	CNY75GB	t <sub>d</sub>		2.5		μs
		CNY75GC	t <sub>d</sub>		2.8		μs
		CNY75GA	t <sub>r</sub>		2.5		μs
Rise time	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 100 \Omega$	CNY75GB	tr		3		μs
		CNY75GC	t <sub>r</sub>		4.2		μs
		CNY75GA	t <sub>f</sub>		2.7		μs
Fall time	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 100 \Omega$	CNY75GB	t <sub>f</sub>		3.7		μs
		CNY75GC	t <sub>f</sub>		4.7	2   2.5   2.8   2.5   3   4.2   2.7   3.7   4.7   0.3   0.3   0.3   4.5   5.5   7   3   4   5   10	μs
		CNY75GA	t <sub>s</sub>		0.3		μs
Storage time	$V_{CC}$ = 5 V, $R_L$ = 100 $\Omega$	CNY75GB	ts		0.3		μs
		CNY75GC	t <sub>s</sub>		2.7   3.7   4.7   0.3   0.3   0.3   4.5   5.5	μs	
		CNY75GA	t <sub>on</sub>		4.5		μs
Turn-on time	$V_{CC}$ = 5 V, $R_L$ = 100 $\Omega$	CNY75GB	t <sub>on</sub>		5.5		μs
		CNY75GC	t <sub>on</sub>		7	10   10   10   10   10   10   10   2   2.5   2.8   2.5   3   4.2   2.7   3.7   4.2   2.7   3.7   4.7   0.3   0.3   0.3   0.3   0.3   0.3   0.3   0.3   0.3   0.3   0.3   0.3   10   6.5   11   25	μs
		CNY75GA	t <sub>off</sub>		3		μs
Turn-off time	$V_{CC}$ = 5 V, $R_L$ = 100 $\Omega$	CNY75GB	t <sub>off</sub>		4		μs
		CNY75GC	t <sub>off</sub>		5		μs
		CNY75GA	t <sub>on</sub>		10		μs
Turn-on time	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$	CNY75GB	t <sub>on</sub>		16.5		μs
		CNY75GC	t <sub>on</sub>		11		μs
		CNY75GA	t <sub>off</sub>		25		μs
Turn-off time	$V_{CC} = 5 \text{ V}, \text{ R}_{L} = 1 \text{ k}\Omega$	CNY75GB	t <sub>off</sub>		20		μs
		CNY75GC	t <sub>off</sub>		37.5		μs



Optocoupler, Phototransistor Output, Vishay Semiconductors with Base Connection

MAXIMUM SAFETY RATINGS <sup>(1)</sup>								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward current		IF			130	mA		
OUTPUT								
Power dissipation		P <sub>diss</sub>			265	mW		
COUPLER	COUPLER							
Rated impulse voltage		V <sub>IOTM</sub>			6	kV		
Safety temperature		T <sub>si</sub>			150	°C		

Note

<sup>(1)</sup> According DIN EN 60747-5-5. This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

INSULATION RATED PARAMETERS								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	$V_{pd}$	1.6			kV		
Partial discharge test voltage -	t <sub>Tr</sub> = 60 s, t <sub>test</sub> = 10 s,	VIOTM	6			kV		
lot test (sample test)	(see figure 1)	V <sub>pd</sub>	1.3			kV		
Insulation resistance	V <sub>IO</sub> = 500 V	R <sub>IO</sub>	10 <sup>12</sup>			Ω		
	$V_{IO}=500~V,~T_{amb}\leq 100~^{\circ}C$	R <sub>IO</sub>	10 <sup>11</sup>			Ω		
	$V_{IO}$ = 500 V, $T_{amb} \le$ 150 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>			Ω		

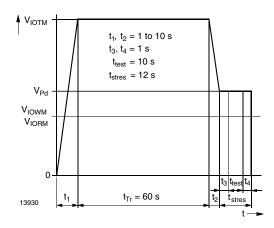


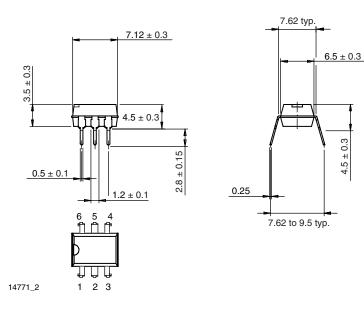
Fig. 1 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5 (VDE 0884)/DIN EN 60747-; IEC60747

Vishay Semiconductors Optocoupler, Phototransistor Output, with Base Connection

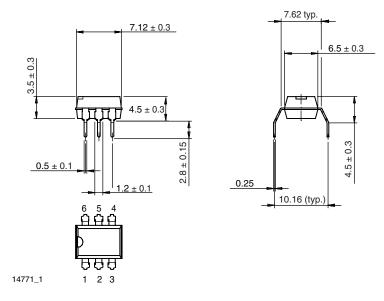


### **PACKAGE DIMENSIONS** in millimeters

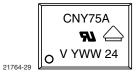
DIP-6



DIP-6, 400 mil



### **PACKAGE MARKING**





Vishay

## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

# **Mouser Electronics**

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

CNY75A CNY75B CNY75C CNY75GA CNY75GB CNY75GC